

P-Channel Power MOSFET

-30V, -64A, 8.5mΩ

FEATURES

- Low $R_{DS(ON)}$ to minimize conductive losses
- Low gate charge for fast power switching
- 100% UIS and R_g tested
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

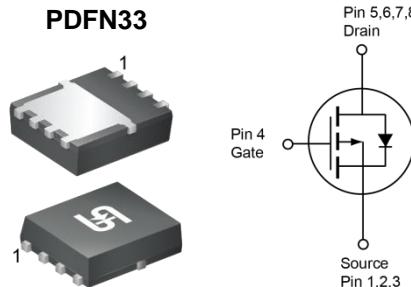
- DC-DC Converters
- Battery Power Management
- Load Switch
- BLDC Motor Drives

KEY PERFORMANCE PARAMETERS		
PARAMETER	VALUE	UNIT
V_{DS}	-30	V
$R_{DS(on)}$ (max)	$V_{GS} = -10V$	8.5
	$V_{GS} = -4.5V$	14
Q_g	27	nC



✓
RoHS
COMPLIANT

HALOGEN
FREE



Note: MSL 1 (Moisture Sensitivity Level) per J-STD-020

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current ^(Note 1)	I_D	-64	A
$T_C = 25^\circ C$		-14	
Pulsed Drain Current	I_{DM}	-256	A
$T_A = 25^\circ C$			
Single Pulse Avalanche Current ^(Note 2)	I_{AS}	-23	A
Single Pulse Avalanche Energy ^(Note 2)	E_{AS}	79	mJ
Total Power Dissipation	P_D	50	W
$T_C = 25^\circ C$		10	
Total Power Dissipation	P_D	2.4	W
$T_A = 25^\circ C$		0.5	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	R_{EJC}	2.5	°C/W
Junction to Ambient Thermal Resistance	R_{EJA}	53	°C/W

Thermal Performance Note: R_{EJA} is the sum of the junction-to-case and case-to-ambient thermal resistances. The case-thermal reference is defined at the solder mounting surface of the drain pins. R_{EJA} is guaranteed by design while R_{ECA} is determined by the user's board design.

ELECTRICAL SPECIFICATIONS ($T_A = 25^\circ C$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV_{DSS}	-30	--	--	V
Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250\mu A$	$V_{GS(TH)}$	-1.2	-1.6	-2.5	V
Gate-Source Leakage Current	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Drain-Source Leakage Current	$V_{GS} = 0V, V_{DS} = -30V$	I_{DSS}	--	--	-1	μA
	$V_{GS} = 0V, V_{DS} = -30V$ $T_J = 125^\circ C$		--	--	-100	
Drain-Source On-State Resistance (Note 3)	$V_{GS} = -10V, I_D = -14A$	$R_{DS(on)}$	--	7.1	8.5	$m\Omega$
	$V_{GS} = -4.5V, I_D = -14A$		--	11	14	
Forward Transconductance (Note 3)	$V_{DS} = -5V, I_D = -14A$	g_{fs}	--	38	--	S
Dynamic (Note 4)						
Total Gate Charge	$V_{GS} = -10V,$ $V_{DS} = -15V, I_D = -14A$	Q_g	--	55	--	nC
Total Gate Charge	$V_{GS} = -4.5V,$ $V_{DS} = -15V, I_D = -14A$	Q_g	--	27	--	
Gate-Source Charge		Q_{gs}	--	9.2	--	
Gate-Drain Charge		Q_{gd}	--	9.9	--	
Input Capacitance	$V_{GS} = 0V, V_{DS} = -15V$ $f = 1.0MHz$	C_{iss}	--	3234	--	pF
Output Capacitance		C_{oss}	--	396	--	
Reverse Transfer Capacitance		C_{rss}	--	251	--	
Gate Resistance	$f = 1.0MHz, \text{open drain}$	R_g	1.6	6	12	Ω
Switching (Note 4)						
Turn-On Delay Time	$V_{GS} = -10V, V_{DS} = -15V,$ $I_D = -14A, R_G = 2\Omega,$	$t_{d(on)}$	--	7.2	--	ns
Turn-On Rise Time		t_r	--	2.6	--	
Turn-Off Delay Time		$t_{d(off)}$	--	56	--	
Turn-Off Fall Time		t_f	--	27	--	
Source-Drain Diode						
Forward Voltage (Note 3)	$V_{GS} = 0V, I_S = -14A$	V_{SD}	--	--	-1	V
Reverse Recovery Time	$I_S = -14A,$ $dI/dt = 100A/\mu s$	t_{rr}	--	23	--	ns
Reverse Recovery Charge		Q_{rr}	--	11	--	nC

Notes:

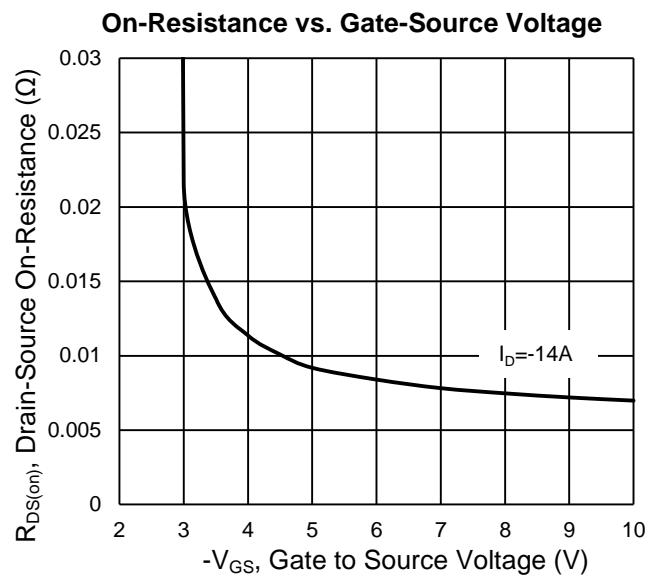
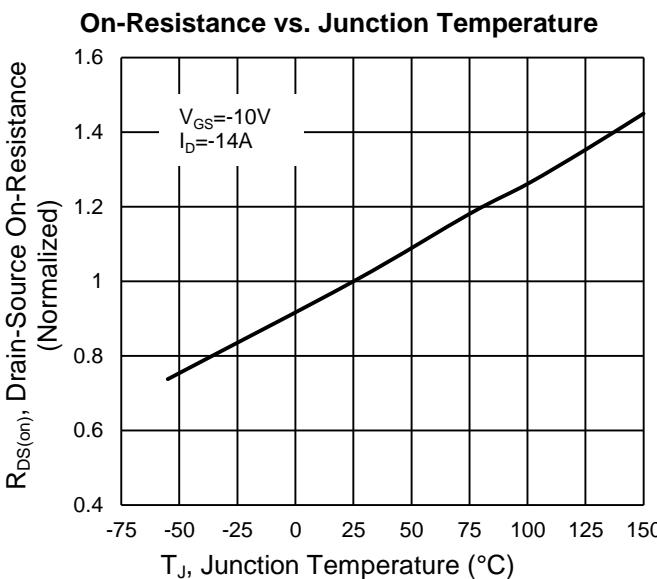
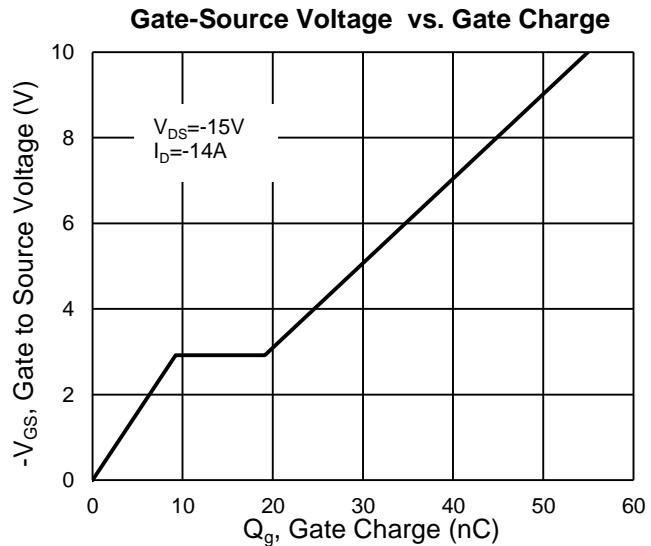
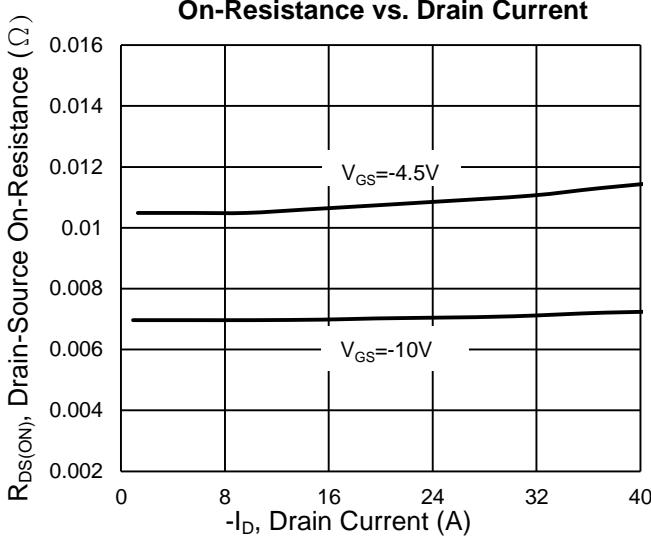
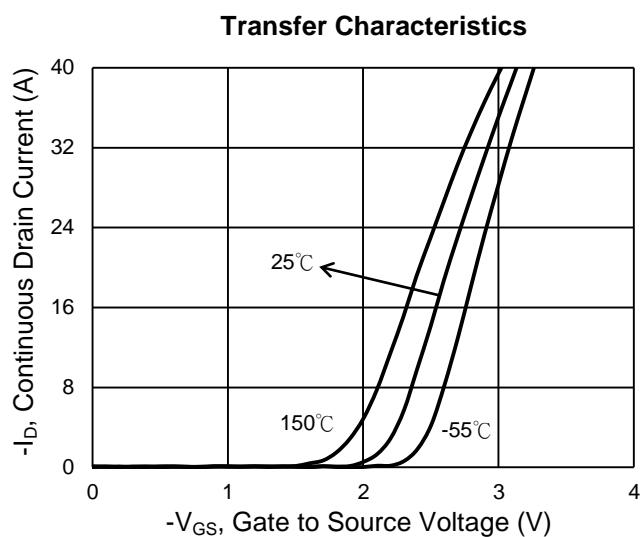
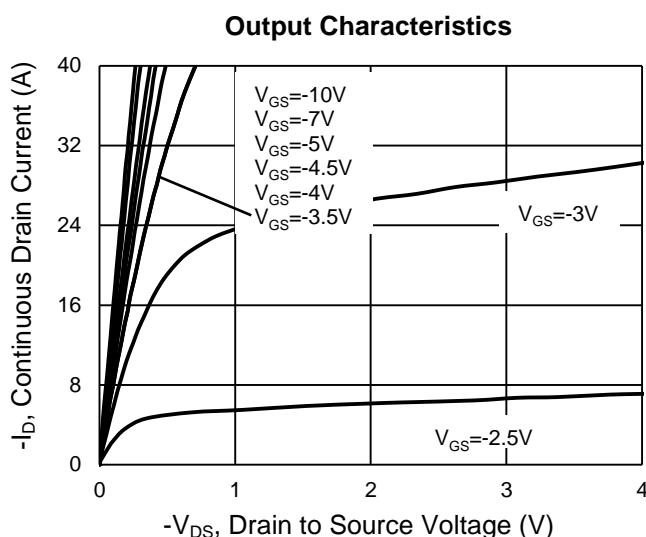
1. Silicon limited current only.
2. $L = 0.3mH, V_{GS} = -10V, V_{DD} = -25V, R_G = 25\Omega, I_{AS} = -23A$, Starting $T_J = 25^\circ C$
3. Pulse test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
4. Switching time is essentially independent of operating temperature.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM085P03CV RGG	PDFN33	5,000pcs / 13" Reel

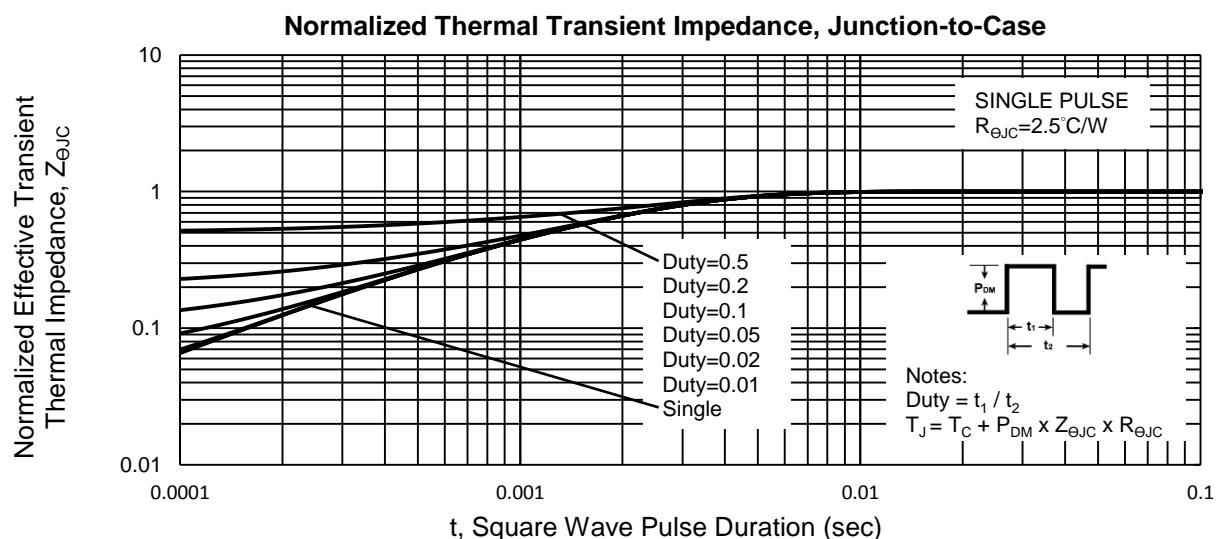
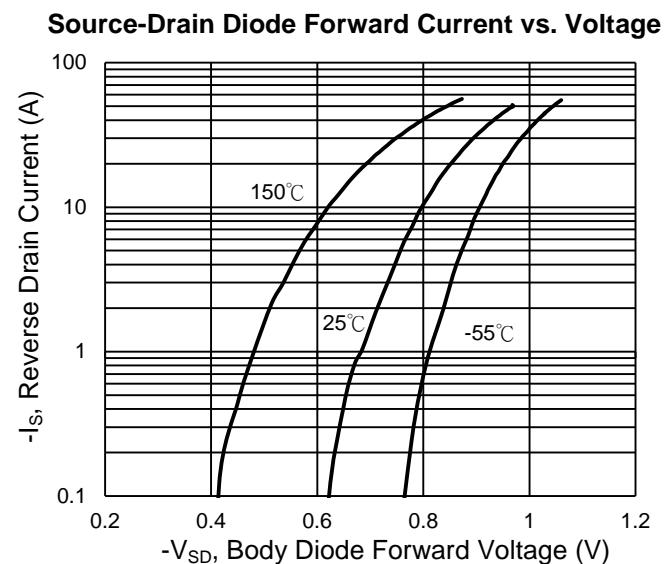
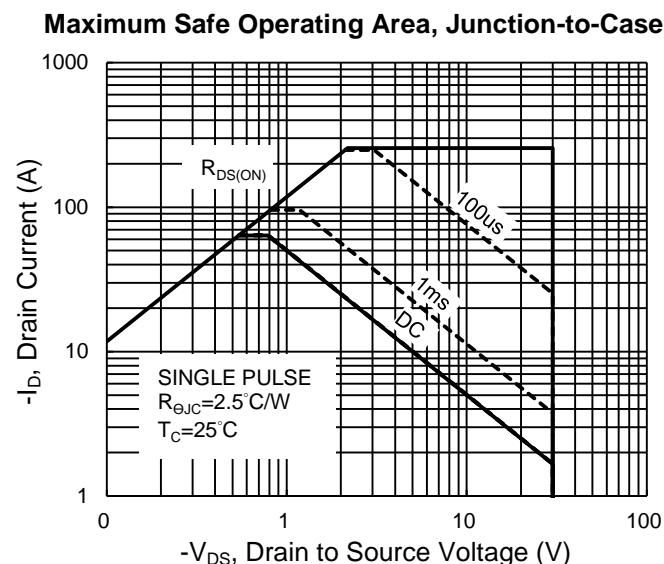
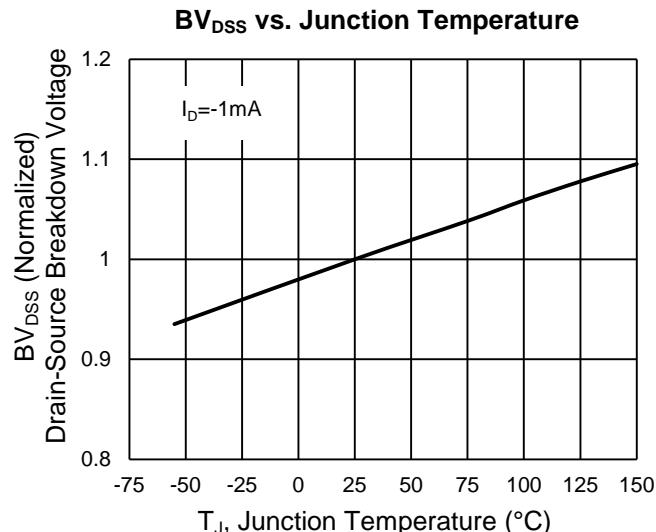
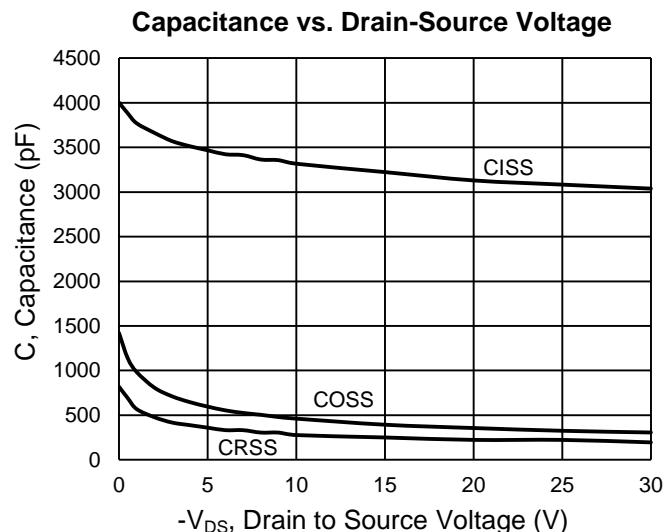
CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)

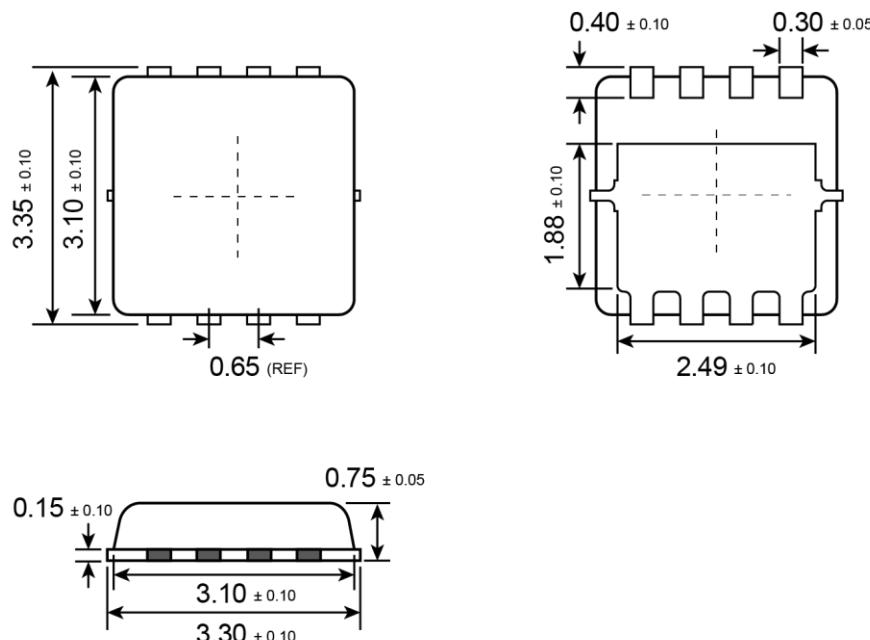
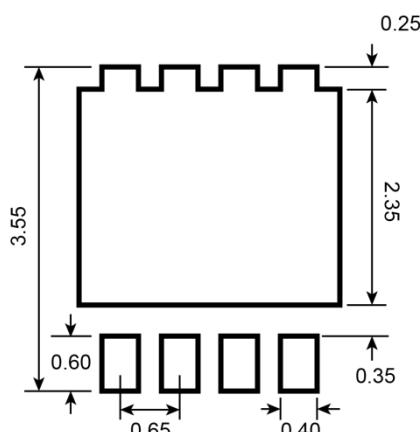


CHARACTERISTICS CURVES

($T_A = 25^\circ\text{C}$ unless otherwise noted)



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

PDFN33

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM
Y = Year Code

M = Month Code for Halogen Free Product

O =Jan **P** =Feb **Q** =Mar **R** =Apr

S =May **T** =Jun **U** =Jul **V** =Aug

W =Sep **X** =Oct **Y** =Nov **Z** =Dec

L = Lot Code (1~9, A~Z)


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